Diode Semiconductor Device - Page 1 of 1



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In	closure Material:
G	ass
0	verall Length:
0.	300 inches
Te	erminal Length:
1.	000 inches
0	verall Diameter:
0.	107 inches
Jo	int Electronic Device Engineering Council/jedec/case Outline Designation:
D	p-7
Μ	ounting Method:
Te	erminal
Fe	eatures Provided:
H	ermetically sealed case
Se	emiconductor Material:
Si	licon
Ve	oltage Rating In Volts Per Characteristic:
11	.7 regulator voltage
Ve	oltage Tolerance In Percent:
-5	.0/+5.0
C	urrent Rating Per Characteristic:
7.	50 milliamperes source cutoff current horsepower metric
Po	ower Rating Per Characteristic:
50	0.0 watts small-signal input power, common-collector preset
Μ	aximum Operating Tempurature Per Measurement Point:
	5.0 degrees celsius ambient air
	erminal Type And Quantity:
	uninsulated wire lead
	nelf Life:
N/	
U	nit Of Measure:
	emilitarization:
N	
	ig:
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